NSN 5961-00-233-7191

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Inclosure Material:

Metal

Overall Length:

Between 0.240 inches and 0.260 inches

Overall Diameter:

Between 0.350 inches and 0.370 inches

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

240.0 breakdown voltage, collector-to-base, emitter open and 240.0 breakdown voltage, collector-to-emitter, base open and 6.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

100.00 milliamperes source cutoff current and 0.02 microamperes zero-gate-voltage source current preset

Power Rating Per Characteristic:

700.0 milliwatts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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